

S/N 09/943134



PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Leonard Forbes et al. Examiner: Tu-Tu Ho
Serial No.: 09/943134 Group Art Unit: 2818
Filed: August 30, 2001 Docket: 1303.020US1
Title: PROGRAMMABLE ARRAY LOGIC OR MEMORY DEVICES WITH
ASYMMETRICAL TUNNEL BARRIERS

COMMUNICATION CONCERNING RELATED APPLICATION(S)

MS RCE
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Applicants would like to bring to the Examiner's attention the following related application(s) in the above-identified patent application:

<u>Serial/Patent No.</u>	<u>Filing Date</u>	<u>Attorney Docket</u>	<u>Title</u>
09/945507	August 30, 2001	1303.014US1	FLASH MEMORY WITH LOW TUNNEL BARRIER INTERPOLY INSULATOR
09/945395	August 30, 2001	1303.019US1	DRAM CELLS WITH REPRESSED FLOATING GATE MEMORY, LOW TUNNEL BARRIER INTERPOLY INSULATOR
09/945498	August 30, 2001	1303.024US1	INTEGRATED CIRCUIT MEMORY DEVICE AND METHOD
09/945512	August 30, 2001	1303.027US1	IN SERVICE PROGRAMMABLE LOGIC ARRAYS WITH LOW TUNNEL BARRIER INTERPOLY INSULATOR
09/945554	August 30, 2001	1303.028US1	SRAM CELLS WITH REPRESSED FLOATING GATE MEMORY, LOW TUNNEL BARRIER INTERPOLY INSULATOR
10/028001	December 20, 2001	1303.035US1	PROGRAMMABLE ARRAY LOGIC OR MEMORY WITH P-CHANNEL DEVICES AND ASYMMETRICAL TUNNEL BARRIERS

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10/081818	February 20, 2002	1303.045US1	ATOMIC LAYER DEPOSITION OF METAL OXIDE AND/OR LOW ASYMMETRICAL TUNNEL BARRIER INTERPOLY INSULATORS
10/177096	June 21, 2002	1303.063US1	GRADED COMPOSITION METAL OXIDE TUNNEL BARRIER INTERPOLY INSULATORS
10/789038	February 27, 2004	1303.024US2	INTEGRATED CIRCUIT MEMORY DEVICE AND METHOD
10/783695	February 20, 2004	1303.019US2	DRAM CELLS WITH REPRESSED FLOATING GATE MEMORY, LOW TUNNEL BARRIER INTERPOLY INSULATORS
10/781035	February 18, 2004	1303.063US2	GRADED COMPOSITION METAL OXIDE TUNNEL BARRIER INTERPOLY INSULATORS
10/788810	February 27, 2004	1303.027US2	IN SERVICE PROGRAMMABLE LOGIC ARRAYS WITH LOW TUNNEL BARRIER INTERPOLY INSULATORS
10/819550	April 7, 2004	1303.019US3	DRAM CELLS WITH REPRESSED FLOATING GATE MEMORY, LOW TUNNEL BARRIER INTERPOLY INSULATORS

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Respectfully submitted,

LEONARD FORBES ET AL.

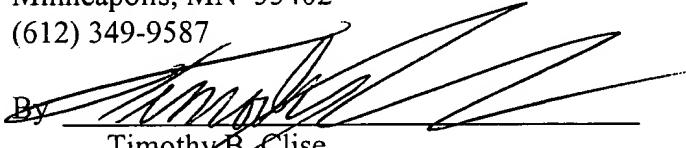
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13 May '04

By


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CERTIFICATE UNDER 37 CFR 1.8: The undersigned hereby certifies that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail, in an envelope addressed to: MS RCE, Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450, on this 13th day of May, 2004.

Name

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